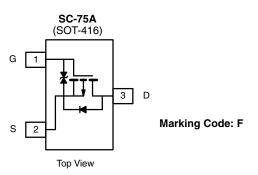


**Vishay Siliconix** 

# P-Channel 60 V (D-S) MOSFET

PRODUCT SUMMARY				
V <sub>DS(min.)</sub> (V)	<b>R<sub>DS(on)</sub> (</b> Ω <b>)</b>	V <sub>GS(th)</sub> (V)	I <sub>D</sub> (mA)	
- 60	4.0 at V <sub>GS</sub> = - 10 V	- 1 to 3.0	- 190	



Ordering Information: Si1021R-T1-GE3 (Lead (Pb)-free and Halogen-free)

### FEATURES

- Halogen-free According to IEC 61249-2-21
  Definition
- TrenchFET<sup>®</sup> Power MOSFETs
- High-Side Switching
- Low On-Resistance: 4  $\Omega$
- Low Threshold: 2 V (typ.)
- Fast Switching Speed: 20 ns (typ.)
- Low Input Capacitance: 20 pF (typ.)
- Miniature Package
- ESD Protected: 2000 V
- Compliant to RoHS Directive 2002/95/EC

#### APPLICATIONS

- Drivers: Relays, Solenoids, Lamps, Hammers, Displays, Memories, Transistors, etc.
- Battery Operated Systems
- Power Supply Converter Circuits
- Solid-State Relays

#### BENEFITS

- Ease in Driving Switches
- Low Offset Voltage
- Low-Voltage Operation
- High-Speed Circuits
- Easily Driven without Buffer
- Small Board Area

ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25 °C, unless otherwise noted)					
Parameter		Symbol	Limit	Unit	
Drain-Source Voltage		V <sub>DS</sub>	- 60	v	
Gate-Source Voltage		V <sub>GS</sub>	± 20	v	
Continuous Drain Current (T <sub>.1</sub> = 150 °C) <sup>a</sup>	T <sub>A</sub> = 25 °C	- I <sub>D</sub>	- 190		
Continuous Drain Current $(T_j = 150^{\circ} C)$	T <sub>A</sub> = 85 °C		- 135	mA	
Pulsed Drain Current <sup>b</sup>		I <sub>DM</sub>	- 650		
Power Dissipation <sup>a</sup>	T <sub>A</sub> = 25 °C	P <sub>D</sub>	250	mW	
	T <sub>A</sub> = 85 °C		130	11100	
Maximum Junction-to-Ambient <sup>a</sup>		R <sub>thJA</sub>	500	°C/W	
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55 to 150	°C	

Notes:

a. Surface mounted on FR4 board.

b. Pulse width limited by maximum junction temperature.



# Si1021R

# Vishay Siliconix



Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Static	•					
Drain-Source Breakdown Voltage	V <sub>DS</sub>	$V_{GS} = 0 V, I_{D} = -10 \mu A$	- 60			
Gate-Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_{D} = -0.25 \text{ mA}$	- 1		- 3.0	V
		$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 10	μA
Cata Dady Laskaga	I <sub>GSS</sub>	$V_{DS} = 0 V, V_{GS} = \pm 10 V$			± 200	
Gate-Body Leakage		$V_{DS} = 0 \text{ V}, \text{ V}_{GS} = \pm 10 \text{ V}, \text{ T}_{J} = 85 ^{\circ}\text{C}$			± 500	nA
		$V_{DS} = 0 V, V_{GS} = \pm 5 V$			± 100	
Zero Gate Voltage Drain Current		$V_{DS} = -50 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$			- 25	
	IDSS	$V_{DS} = -50 \text{ V}, \text{ V}_{GS} = 0 \text{ V}, \text{ T}_{J} = 85 \text{ °C}$			- 250	ĺ
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS}$ = -10 V, $V_{GS}$ = - 4.5 V	- 50			
		$V_{DS} = -10 \text{ V}, \text{ V}_{GS} = -10 \text{ V}$ - 600				mA
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	V <sub>GS</sub> = - 4.5 V, I <sub>D</sub> = - 25 mA			8	Ω
		V <sub>GS</sub> = - 10 V, I <sub>D</sub> = - 500 mA			4	
		$V_{GS}$ = - 10 V, $I_{D}$ = - 500 mA, $T_{J}$ = 125 °C			6	
Forward Transconductance	9 <sub>fs</sub>	V <sub>DS</sub> = - 10 V, I <sub>D</sub> = - 100 mA	80			mS
Diode Forward Voltage <sup>a</sup>	V <sub>SD</sub>	V <sub>DS</sub> = - 200 mA, V <sub>GS</sub> = 0 V	80			V
Dynamic	•					
Total Gate Charge	Qg			1.7		
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS}$ = - 30 V, $V_{GS}$ = - 15 V, $I_D \cong$ - 500 mA		0.26		nC
Gate-Drain Charge	Q <sub>gd</sub>			0.46		
Input Capacitance	C <sub>iss</sub>			23		
Output Capacitance	C <sub>oss</sub>	V <sub>DS</sub> = - 25 V, V <sub>GS</sub> = 0 V, f = 1 MHz		10		pF
Reverse Transfer Capacitance	C <sub>rss</sub>	1		5		
Switching <sup>b</sup>					I	
Turn-On Time	t <sub>ON</sub>	V <sub>DD</sub> = - 25 V, R <sub>I</sub> = 150 Ω,		20		
Turn-Off Time	tOFF	$I_D \cong$ - 200 mA, $V_{GEN}$ = - 10 V, $R_g$ = 10 $\Omega$		35		ns

Notes:

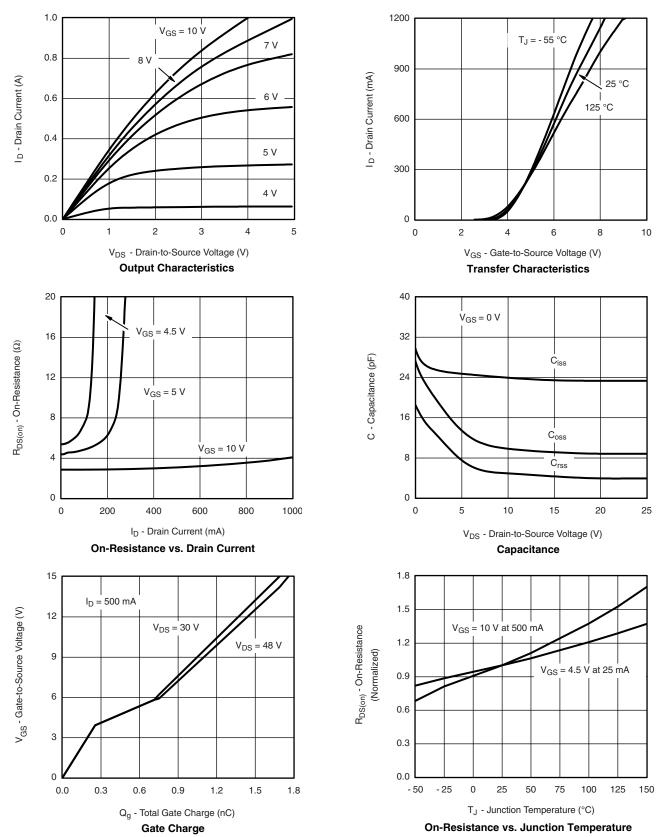
a. Pulse test; pulse width  $\leq$  300  $\mu s,$  duty cycle  $\leq$  2 %.

b. Switching time is essentially independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



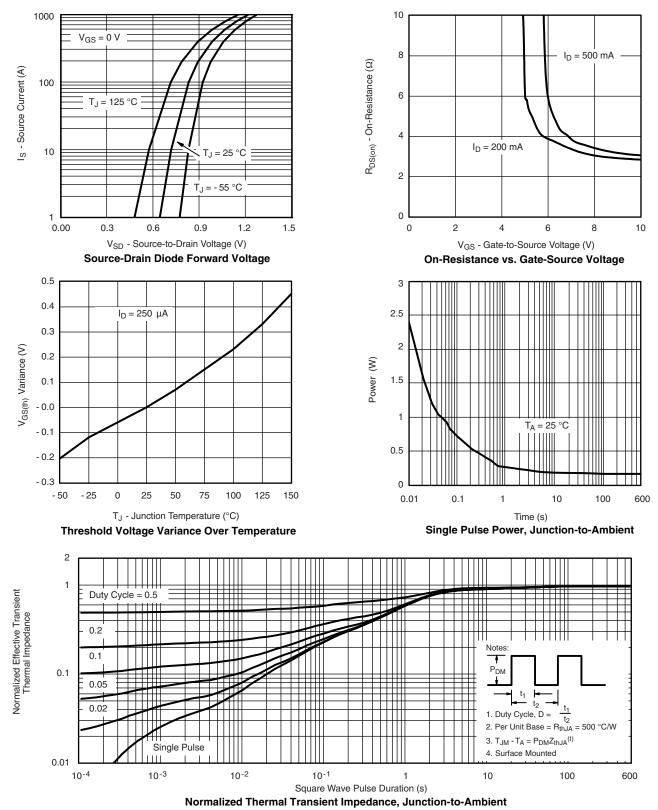
## **TYPICAL CHARACTERISTICS** ( $T_A = 25 \text{ °C}$ , unless otherwise noted)



## Vishay Siliconix



## **TYPICAL CHARACTERISTICS** ( $T_A = 25 \text{ °C}$ , unless otherwise noted)

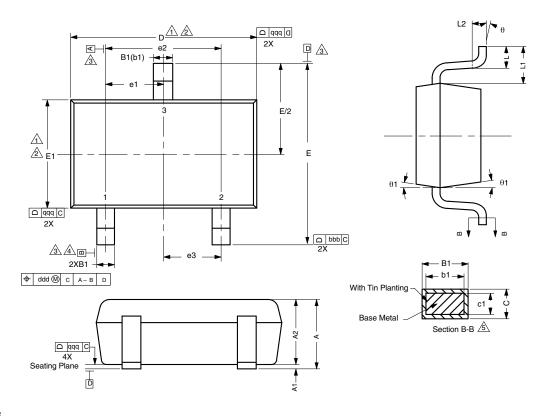


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## SC-75A: 3 Leads



#### DWG: 5868

#### Notes

Dimensions in millimeters will govern.

- ⚠Dimension D does not include mold flash, protrusions or gate burrs. Mold flash protrusions or gate burrs shall not exceed 0.10 mm per end. Dimension E1 does not include Interlead flash or protrusion. Interlead flash or protrusion shall not exceed 0.10 mm per side.
- 2 Dimensions D and E1 are determined at the outmost extremes of the plastic body exclusive of mold flash, tie bar burrs, gate burrs and interlead flash, but including any mismatch between the top and bottom of the plastic body.
- A Datums A, B and D to be determined 0.10 mm from the lead tip.

A Terminal positions are shown for reference only.

These dimensions apply to the flat section of the lead between 0.08 mm and 0.15 mm from the lead tip.

DIMENSIONS	TOLERANCES
aaa	0.10
bbb	0.10
ссс	0.10
ddd	0.10

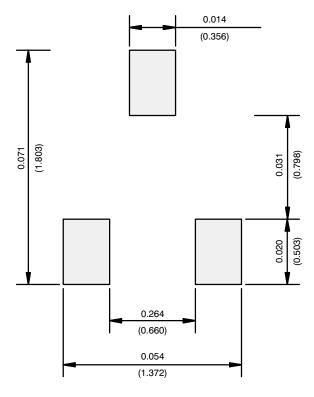
DIM.	MILLIMETERS			NOTE
DIN.	MIN.	NOM.	MAX.	NOTE
A	-	-	0.80	
A1	0.00	-	0.10	
A2	0.65	0.70	0.80	
B1	0.19	-	0.24	5
b1	0.17 - 0.21		0.21	
с	0.13	-	0.15	5
c1	0.10	-	0.12	5
D	1.48	1.575	1.68	1, 2
E	1.50	1.60	1.70	
E1	0.66	0.76	0.86	1, 2
e1	0.50 BSC			
e2	1.00 BSC			
e3	0.50 BSC			
L	0.15	0.205	0.30	
L1	0.40 ref.			
L2	0.15 BSC			
q	0°	-	8°	
q1	4°	-	10°	



# Application Note 826

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## **RECOMMENDED MINIMUM PADS FOR SC-75A: 3-Lead**



Recommended Minimum Pads Dimensions in Inches/(mm)

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